ADJD-E622-QR999 RGB Color Sensor in QFN Package

Data Sheet



Description

ADJD-E622-QR999 is a high performance, small in size, cost effective light to voltage converting sensor. The sensor combines a photodiode array and three transimpedance amplifiers in a single monolithic CMOS IC solution. With a Red (R), Green (G) and Blue (B) color filters coated over the photodiode array, the sensor converts RGB light to analog voltage outputs, denoted by VROUT, VGOUT and VBOUT, respectively. The sensor is packaged in a 5x5x0.75 [mm] surface mount QFN-16 package.

Applications

- Ideal choice of light sensor in automotive applications such as dashboard lighting, automotive interior lighting, infotainment and navigational panel.
- Other potential applications are such as environmental lighting, cabin lighting, decorative lighting, general color detection, industrial process, etc.
- Can also be coupled with Avago Technologies' patented color controller, HDJD-J822, to form a closed loop color management system

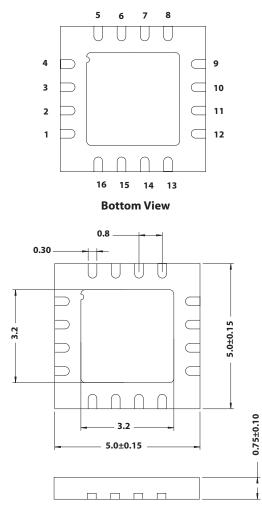
Features

- Convert light to R,G,B voltage output
- Monolithic CMOS IC solution comprises of an array of photodiode coated with R,G, B color filter and integrated with transimpedance amplifier.
- Independent gain selection options for each R,G,B channel
- 3 sets of 3x3 photodiode array design to minimize the effect of contamination and optical aperture misalignment
- Qualified per Automotive AEC-Q100 Standard (Grade 3)
- Robust package and small in size 5x 5x 0.75 mm

ESD WARNING: Standard CMOS handling precautions should be observed to avoid static discharge.

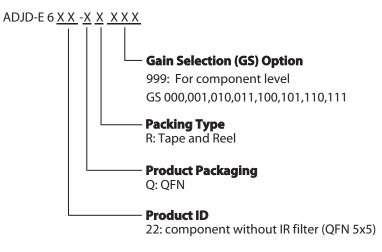
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Package Dimension



Note: Dimensions are in millimeters (mm)

Part Numbering System



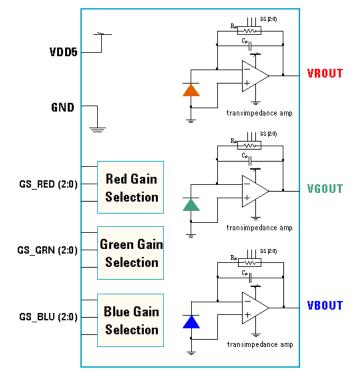
Theory of Operation

The integral R,G,B color filters on the photodiode array detect the R,G,B components of the light falling on the sensor. The photodiode convert the R,G,B light components into photocurrents. The integrated transimpedence amplifiers for R,G,B components then converts the photocurrent to analog voltage outputs. The voltage output of each R,G,B channel increases linearly with increasing light intensity.

Pin Out for ADJD-E622-QR999

Pin	Pin Name	Normal Operation
Pin 1	VB _{OUT}	Analog output voltage for BLUE
Pin 2	VG _{OUT}	Analog output voltage for GREEN
Pin 3	VR _{OUT}	Analog output voltage for RED
Pin 4	VDD	5V DC Supply
Pin 5	GSGRN2	Gain Selection Green bit 2
Pin 6	GSGRN1	Gain Selection Green bit 1
Pin 7	GSRED2	Gain Selection Red bit 2
Pin 8	GSRED1	Gain Selection Red bit 1
Pin 9	GSRED0	Gain Selection Red bit 0
Pin 10	NC	No connection
Pin 11	NC	No connection
Pin 12	GSBLUE0	Gain Selection Blue bit 0
Pin 13	GSBLUE1	Gain Selection Blue bit 1
Pin 14	GSBLUE 2	Gain Selection Blue bit 2
Pin 15	GSGRN 0	Gain Selection Green bit 0
Pin 16	GND	Ground

Sensor IC Block Diagram



Absolute Maximum Ratings ^[1,2]

Parameter	Symbol	Min	Max	Unit	Notes
Supply Voltage	V _{DD}	4.5	5.5	V	
Storage Temperature	Ts	-50	105	°C	
Operating Temperature	T _A	-40	85	°C	
Human Body Model ESD Rating	ESD _{HBM}		8	kV	
Machine Model ESD Rating	ESD _{MM}		200	V	
Charge Device Model ESD Rating [3]	ESD _{CDM}		500	V	

Note:

1. Subjecting the part to stresses beyond those listed under this section may cause permanent damage to the device. These are stress ratings only and do not imply that the devices will function beyond these ratings. Exposure to the extremes of these conditions for extended periods may affect device reliability.

2. Unless otherwise specified, voltages are referenced to ground.

3. Maximum ESD rating for corner pin is 750V

Recommended Operating Conditions

Parameter	Sym.	Min.	Тур.	Max.	Units	Notes
Operating Temperature	T _A	0	25	70	°C	
Supply Voltage	V_{DD}	4.5	5.0	5.5	V	A decoupling capacitor of 100nF between V _{DD} and ground is recommended.

Vout

RC Lowpass Filter

Remarks:

- 1. The device is with moisture sensitivity level 3.
- 2. For optimized signal output, RC filters must be added at each of the R, G and B voltage output.

Gain Selection	Rext	Cext	
GS:000 to GS:101	15kΩ	1nF	
GS:110 to GS:111	15kΩ	6.8nF	
		F	Red Channel
gnal Gererator	LED	3	VRout Rext

For illustration purpose, only red channel is shown. The same circuit applies to green and blue channel.

Operating Conditions and Electrical Requirements

Parameter	Sym.	Remark	Min.	Тур.	Max.	Unit	
Dark voltage	V _D	Ee = 0			20	mV	
Max. output voltage swing	V _{omax}			4.7		V	
Supply current	I _{DD}	Ee = 0		2.4		mA	
Irradiance	Re GS:111, λ_P = 460 nm ^[2] (Blue Channel)			12		V/	
Responsivity		GS:111, λ_P = 542 nm ^[3] (Green Channel)		18		(mW/cm²)	
		GS:111, λ_{P} = 645 nm $^{[4]}$ (Red Channel)		26		-	
Irradiance	Re	GS:110, λ_P = 460 nm ^[2] (Blue Channel)		10		V/	
Responsivity		GS:110, λ_P = 542 nm ^[3] (Green Channel)		14		(mW/cm ²)	
		GS:110, λ_{P} = 645 nm $^{[4]}$ (Red Channel)		20		_	
Irradiance	Re	GS:101, λ_{P} = 460 nm $^{\scriptscriptstyle [2]}$ (Blue Channel)		7		V/	
Responsivity		GS:101, λ_P = 542 nm ^[3] (Green Channel)		11		(mW/cm ²)	
		GS:101, λ_P = 645 nm ^[4] (Red Channel)		16		_	
Irradiance	Re	GS:100, λ_P = 460 nm ^[2] (Blue Channel)		6		V/	
Responsivity		GS:100, λ_P = 542 nm ^[3] (Green Channel)		8		(mW/cm²) 	
		GS:100, λ_{P} = 645 nm ^[4] (Red Channel)		12		—	
Irradiance	Re	GS:011, λ_P = 460 nm ^[2] (Blue Channel)		5		V/	
Responsivity		GS:011, λ_{P} = 542 nm ^[3] (Green Channel)		6		(mW/cm²)	
		GS:011, λ_{P} = 645 nm $^{\scriptscriptstyle[4]}$ (Red Channel)		9		_	
Irradiance	Re	GS:010, λ_P = 460 nm ^[2] (Blue Channel)		4		V/	
Responsivity		GS:010, λ_P = 542 nm ^[3] (Green Channel)		5		(mW/cm ²)	
		GS:010, λ_P = 645 nm ^[4] (Red Channel)		7		_	
Irradiance	Re	GS:001, λ_{P} = 460 nm ^[2] (Blue Channel)		3		V/	
Responsivity		GS:001, λ_P = 542 nm ^[3] (Green Channel)		4		(mW/cm²)	
		GS:001, λ_{P} = 645 nm ^[4] (Red Channel)		6		—	
Irradiance	Re	GS:000, λ_P = 460 nm ^[2] (Blue Channel)		2		V/	
Responsivity		GS:000, λ_P = 542 nm ^[3] (Green Channel)		3		(mW/cm ²)	
		GS:000, λ_P = 645 nm ^[4] (Red Channel)		4		—	
Saturation		GS:111, λ_P = 460 nm ^[2] (Blue Channel)		0.39		mW/cm ²	
Irradiance [5]		GS:111, λ_P = 542 nm ^[3] (Green Channel)		0.26		_	
		GS:111, $\lambda_P = 645$ nm ^[4] (Red Channel)		0.18		_	
Saturation		GS:110, λ_P = 460 nm ^[2] (Blue Channel)		0.47		mW/cm ²	
Irradiance [5]		GS:110, λ_P = 542 nm ^[3] (Green Channel)		0.34		_	
		GS:110, $\lambda_P = 645$ nm ^[4] (Red Channel)		0.23			

Electrical Characteristics at V_DD = 5V, T_A = 25 °C, RL = 68 k \Omega

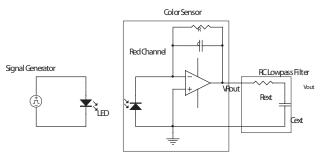
Parameter	Sym.	Remark	Min.	Тур.	Max.	Unit	
Saturation		GS:101, λ_P = 460 nm ^[2] (Blue Channel)		0.67		mW/cm2	
Irradiance ^[5]		GS:101, $\lambda_P = 542$ nm ^[3] (Green Channel)		0.43		-	
		GS:101, $\lambda_P = 645$ nm ^[4] (Red Channel)		0.29		-	
Saturation		GS:100, $\lambda_P = 460 \text{ nm}^{[2]}$ (Blue Channel)		0.78		mW/cm2	
Irradiance [5]		GS:100, $\lambda_P = 542$ nm ^[3] (Green Channel)		0.59			
		GS:100, $\lambda_P = 645 \text{ nm}^{[4]}$ (Red Channel)		0.40		_	
Saturation		GS:011, λ_P = 460 nm ^[2] (Blue Channel)		0.94		mW/cm2	
Irradiance [5]		GS: 011, $\lambda_P = 542 \text{ nm}^{[3]}$ (Green Channel)		0.78		_	
		GS: 011, $\lambda_P = 645 \text{ nm}^{[4]}$ (Red Channel)		0.53			
Saturation Irradiance ^[5]		GS:010, λ_P = 460 nm ^[2] (Blue Channel)		1.18		mW/cm2	
		GS:010, $\lambda_P = 542$ nm ^[3] (Green Channel)		0.94		_	
		GS:010, λ_P = 645 nm ^[4] (Red Channel)		0.71			
Saturation		GS:001, $\lambda_P =$ 460 nm ^[2] (Blue Channel)		1.57		mW/cm2	
Irradiance ^[5]		GS:001, λ_P = 542 nm ^[3] (Green Channel)		1.18		-	
		GS:001, $\lambda_P = 645$ nm ^[4] (Red Channel)		0.85		_	
Saturation		GS:000, $\lambda_P =$ 460 nm ^[2] (Blue Channel)		2.35		mW/cm2	
Irradiance [5]		GS:000, λ_P = 542 nm ^[3] (Green Channel)		1.57		-	
		GS:000, $\lambda_P = 645$ nm ^[4] (Red Channel)		1.34		_	
Output rise time	t _r	GS:000 to GS101 Test Condition: Refer to note ^[1] (min Vo = 0V, peak Vo = 2V)		45		μs	
		GS:110 to GS:111 Test Condition: Refer to note ^[1] (min Vo = 0V, peak Vo = 2V)		220		μs	
Output fall time	t _f	GS:000 to GS101 Test Condition: Refer to note ^[1] (min Vo = 0V, peak Vo = 2V)		50		μs	
		GS:110 to GS:111 Test Condition: Refer to note ^[1] (min Vo = $0V$, peak Vo = $2V$)		240		μs	

Notes:

- 1. Test condition: The rise and fall time is measured with RC lowpass filter added to sensor output:
- 2. Test condition: using blue diffuse light of peak wavelength (λ_P) 460nm and spectral half width ($\Delta\lambda \lambda_2$) 25nm as light source.
- 3. Test condition: using green diffuse light of peak wavelength (λ_P) 542nm and spectral half width ($\Delta\lambda \lambda_2$) 35nm as light source.
- 4. Test condition: using red diffuse light of peak wavelength (λ_P) 645nm and spectral half width ($\Delta\lambda V_2$) 20nm as light source.
- Saturation irradiance = (Max output voltage swing)/(Irradiance responsivity)

Remarks: For illustration purpose, only red channel is shown. The same circuit applies to green and blue channel.

Gain Selection	Rext	Cext
GS:000 to GS:101	15kΩ	1nF
GS:110 to GS:111	15kΩ	6.8nF





Gain Selection	Feedback	Resistor	Table
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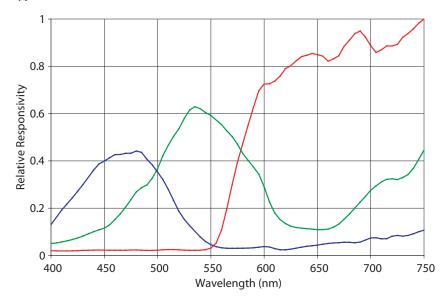
GS: Bit 2	GS: Bit 1	Bit 0	Feedback Resistor, RF
0	0	0	1.9 MΩ
0	0	1	2.5 MΩ
0	1	0	3.2 MΩ
0	1	1	4.1 MΩ
1	0	0	5.3 MΩ
1	0	1	7 ΜΩ
1	1	0	9 MΩ
1	1	1	11.7 MΩ



- 1. Gains selections, GS: Bit 2 Bit 1 Bit 0 are applicable for each Red, Green and Blue Channel.
- 2. Gain selections for each channel can be selected independently of each other.
- 3. Feedback resistor value is proportional to responsivity. Refer to block diagram below.
- 4. 0 indicates that the pin is connected to ground. 1 indicates no connection.

Feedback resistor R_F C_P C_P transimpedance amp

Typical Characteristics





Note:

Test condition is when Gain Selection Jumpers are set to					
GSBLUE2=1	GSGRN2=1	GSRED2=1			
GSBLUE1=1	GSGRN1=1	GSRED1=1			
GSBLUE0=1	GSGRN0=1	GSRED0=1			

in which 0=connect to Ground, 1=no connection. Refer to Gain Selection Feedback Resistor Table.

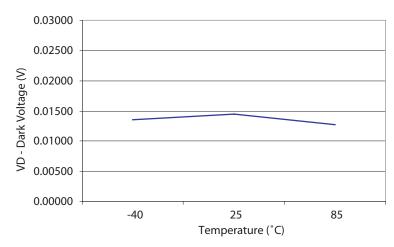


Figure 2. Dark Voltage vs Operating Temperature

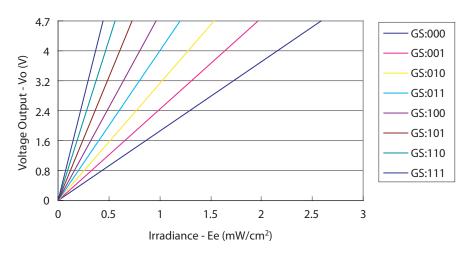


Figure 3. Voltage Output of Blue Channel vs Irradiance (lp = 460 nm)

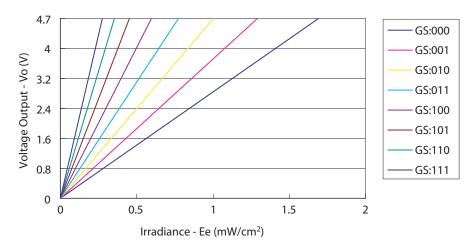


Figure 4. Voltage Output of Green Channel vs Irradiance (Ip = 542 nm)

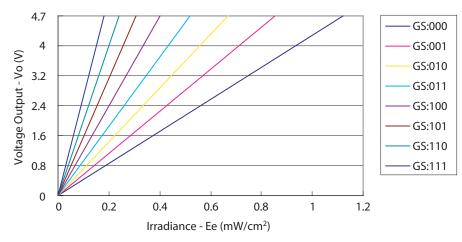


Figure 5. Voltage Output of Red Channel vs Irradiance (lp = 645 nm)

Recommended Reflow Profile

It is recommended that Henkel Pb-free solder paste LF310 be used for soldering ADJD- E622-QR999. Below is the recommended reflow profile.

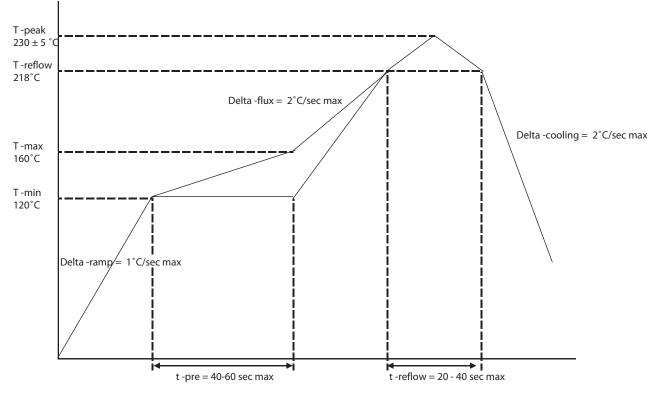
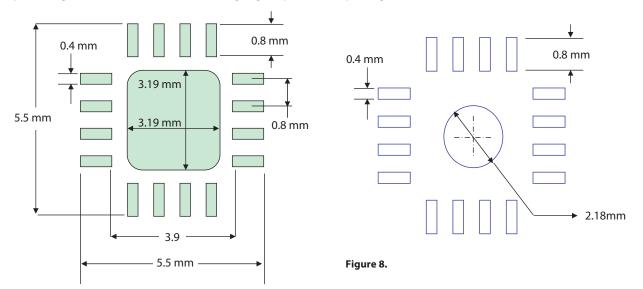


Figure 6. Recommended Reflow Soldering Profile

16 Lead QFN Recommended PCB Land Pad Design

IPC-SM-782 is used as the standard for the PCB landpad design. Recommended PCB finishing is gold plated.



16 Lead QFN Recommended Stencil Design

package is recommended.

A stencil thickness of 2.18mm (6mils) for this QFN

Figure 7.

Recommendations for Handling and Storage of ADJD E622 QR999

This product is qualified as Moisture Sensitive Level 3 per Jedec J-STD-020. Precautions when handling this moisture sensitive product is important to ensure the reliability of the product. Do refer to Avago Application Note AN5305 Handling Of Moisture Sensitive Surface Mount Devices for details.

A. Storage before use

- Unopened moisture barrier bag (MBB) can be stored at 30°C and 90%RH or less for maximum 1 year
- It is not recommended to open the MBB prior to assembly (e.g. for IQC)
- It should also be sealed with a moisture absorbent material (Silica Gel) and an indicator card (cobalt chloride) to indicate the moisture within the bag

B. Control after opening the MBB

- The humidity indicator card (HIC) shall be read immediately upon opening of MBB
- The components must be kept at <30°C/60%RH at all time and all high temperature related process including soldering, curing or rework need to be completed within 168hrs

C. Control for unfinished reel

- For any unused components, they need to be stored in sealed MBB with desiccant or desiccator at <5%RH

D. Control of assembled boards

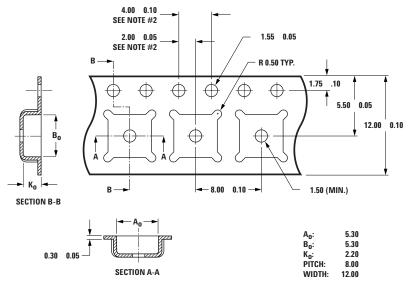
- If the PCB soldered with the components is to be subjected to other high temperature processes, the PCB need to be stored in sealed MBB with desiccant or desiccator at <5%RH to ensure no components have exceeded their floor life of 168hrs

E. Baking is required if:

- "10%" or "15%" HIC indicator turns pink
- The components are exposed to condition of >30°C/60%RH at any time.
- The components floor life exceeded 168hrs
- Recommended baking condition (in component form): 125°C for 24hrs

Package Tape and Reel Dimensions

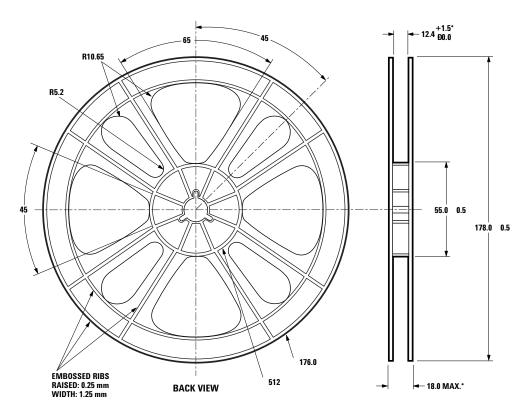
Carrier Tape Dimensions



NOTES:

A O AND BO MEASURED AT 0.3 mm ABOVE BASE OF POCKET.
AO AND BO MEASURED AT 0.3 mm ABOVE BASE OF POCKET.
DITCHES CUMULATIVE TOLERANCE IS 0.2 mm.
JUMENSIONS ARE IN MILLIMETERS (mm).

Reel Dimensions



NOTES: 1. *MEASURED AT HUB AREA. 2. ALL FLANGE EDGES TO BE ROUNDED.

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